Synergistic effect of workfunction and acoustic impedance mismatch for improved thermoelectric performance in GeTe/WC composite

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**Abstract:** The preparation of composite materials is promising for concurrent optimization of electrical and thermal transport properties to realize an improved thermoelectric (TE) performance. We report the effect of percolation network and acoustic impedance mismatch (AIM) on TE properties of \((1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}\) composite. In particular, a composite consisting of Mn and Sb co-doped GeTe as a matrix and WC (tungsten carbide) as a dispersed phase is prepared, and its structural and TE properties are investigated. The simultaneous increase in the electrical conductivity \((\sigma)\) and Seebeck coefficient \((\alpha)\) with WC volume fraction \((z)\) results in an enhanced power factor \((\alpha^2\sigma)\) in the composite. The rise in \(\sigma\) is attributed to increased carrier mobility in the composite, which is further analyzed from the work function measurement using the Kelvin probe force microscopy technique. The difference in elastic properties (sound velocity) between \(\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}\) and WC results in a high AIM that leads to a large interface thermal resistance \((R_{\text{int}})\) between the phases. The correlation between \(R_{\text{int}}\) and the Kapitza radius results in reduced phonon thermal conductivity \((\kappa_{\text{ph}})\) of the composite and is discussed using the Bruggeman asymmetrical model. The simultaneous effect of improvement in \(\alpha^2\sigma\) and reduction in \(\kappa_{\text{ph}}\) results in a maximum figure of merit \((zT)\) of 1.93 at 773 K for \((1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}\) composite for \(z=0.010\), with an average \(zT\) \((zT_{\text{av}})\) of 1.02 for a temperature difference \((\Delta T)\) of 473 K. This study shows promise to achieve higher \(zT_{\text{av}}\) across a wide range of composite materials having similar electronic structure and different elastic properties.

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1. Introduction

The majority of energy generated from several energy sources is wasted during practical applications. Therefore a waste heat recovery technology is essential for the efficient use of these energy resources. Thermoelectric (TE) energy conversion technology that can harvest waste heat energy using temperature gradient without emitting pollutions is a propitious solution for waste heat recovery and niche power resources.\cite{1,2} The usefulness of TE materials depends on its figure of merit ($zT$), defined as

$$zT = \frac{\alpha^2 \sigma}{(k = \kappa_{ph} + \kappa_e) T}$$ \hspace{1cm} (1)

where $T$ is absolute temperature, $\alpha^2 \sigma$ known as power factor that includes Seebeck coefficient ($\alpha$), and electrical conductivity ($\sigma$), and $\kappa$ is total thermal conductivity consists of electronic thermal conductivity ($\kappa_e$) and phonon thermal conductivity ($\kappa_{ph}$). The strong coupling between $\sigma$, $\alpha$, and $\kappa_e$ with trade-off relationship is challenging to achieve a high $zT$ in a single system.\cite{3,4}

The electrical transport has been optimized through several innovative transport mechanisms to achieve enhanced $\alpha^2 \sigma$ in single-phase materials.\cite{5–7} Further, the reduction in $\kappa_{ph}$ has been exemplified in literature through several strategies that amplify the phonon scattering, including lattice defects\cite{8,9}, artificial superlattices\cite{10}, mass disorder\cite{11}, nanostructuring\cite{12}, preparation of composite materials\cite{13,14}. However, scattering of phonons in TE materials via impurities, lattice anharmonicity, and defects also reduces $\sigma$ due to the scattering of charge carriers.\cite{3}

Moreover, the preparation of composite materials is promising for concurrent optimization of electrical and thermal transport properties to realize an improved TE performance.\cite{15–20} Simultaneous effect of carrier energy filtering and enhanced phonon scattering at the interface between Bi$_{0.4}$Sb$_{1.6}$Te$_3$/Cu$_2$Se nanocomposite results in an enhanced $zT$ (\~1.6 at 488 K).\cite{16} Improvement in $zT$ (\~1.85) is obtained for the PbTe-PbSe composite due to the synergistic effect of reducing $\kappa_{ph}$ and improving $\alpha^2 \sigma$.\cite{21} A notable reduction in $\kappa_{ph}$ was also observed in several composites with nanostructure secondary phase.\cite{22,23} The lowering of $\kappa_{ph}$ in nanostructured composite materials is mainly attributed to the quantum size effects.\cite{16,24–26} The studies in literature rarely consider the influence of interface thermal resistance ($R_{int}$),
which originates from the acoustic impedance mismatch (AIM) between the phases on $\kappa_{ph}$.\[^{[27]}\]

However, $R_{int}$ is often used to explain the heat transport mechanism in ceramic and polymer composites, including ZnS/diamond\[^{[27]}\], SiC/Al\[^{[28]}\], glass/epoxy.\[^{[29]}\] These reports along with our previous studies on composite materials demonstrate that $R_{int}$ between the phases of the composite is a crucial parameter to design TE composite materials with desired $\kappa_{ph}$.\[^{[14,30]}\]

GeTe based materials are promising for TE application in the mid-temperature range (500-800 K). However, pristine GeTe suffers from the intrinsic Ge vacancies that result in a high hole carrier concentration ($\sim10^{21}$ cm$^{-3}$), high thermal conductivity ($\sim$8 W·m$^{-1}$·K$^{-1}$), and low Seebeck coefficient ($\sim$30 $\mu$V·K$^{-1}$) and hence poor $zT$.\[^{[31]}\] Our previous report shows that the simultaneous effect of engineering band structure and lattice dynamics improves $zT$ in Mn-Sb co-doped GeTe at 773 K.\[^{[32]}\]

Herein, we demonstrate a composite system considering the attuned electronic structure and mismatched elastic properties to improve $zT$ for GeTe based system. For this purpose, tungsten carbide (WC) as a second phase is used to prepare composite material with Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te. WC possesses higher electrical and thermal conductivity than Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te. The larger difference in elastic properties between Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te and WC has been used to control $\kappa_{ph}$ in the composite using $R_{int}$ between the phases, estimated using AIM and the Debye model. In particular, the effect of WC on electrical transport has been analyzed using the work function of both the materials, measured by the Kelvin probe force microscopy technique. The $\kappa_{ph}$ in the composite is analyzed using the Bruggeman asymmetrical model, which considers $R_{int}$ between the phases.

2. Results and Discussion

2.1. Structural Characterization:

X-ray diffraction pattern of the (1-z)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/(z)WC composite is shown in Fig. 1. Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te shows a rhombohedral structure at 300 K, having the following lattice parameters in a hexagonal setting: $a=b=4.1645\text{Å}$, $c=10.0232\text{Å}$. The diffraction intensity of WC are not prominently observed due to its lower volume fraction in the composite. However, the maximum intensity peak of WC is observed in the log-scale (inset of Fig. 1) and confirms its
presence in the composite. It is seen that the intensity corresponding to the WC phase increases with the increase in the WC volume fraction \( z \) in the composite.

![X-ray diffraction pattern](image)

Figure 1: X-ray diffraction pattern for \((1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}\) composite. Inset shows the zoom-in image in log-scale depicting the presence of the diffraction pattern due to WC. The Miller indices and Bragg’s position for \( \text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te} \) and WC are marked.

Fig. 2(a-d) shows the scanning electron microscope (SEM) image for the polished surface of the \((1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}\) composite. Fig. 2(a) depicts the SEM image of \( \text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te} \) sintered pellet, and it shows a homogeneous nature of the sample. The SEM image of WC powder, used for preparing the composites, is shown in Fig. 2(b). It is observed that the particle sizes of the WC lie in the range of 150-200 nm. In the composite samples, spherical WC particles are surrounded by \( \text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te} \) grains (Fig.2(c-d)). The WC particles are uniformly distributed at the grain boundary, and their concentration increases with the increase in the volume fraction \( z \) in the composite. The bulk density of the sintered pellet is measured using sample mass and its geometrical volume. The relative density of all the samples lies in the range of 98%-99%. Fig. 2(e) shows the energy dispersive x-ray spectra of the composite sample with \( z=0.010 \). The zoom-in image for the same sample is shown in the inset.
of Fig. 2(e). The presence of WC and other constituents of GeTe is confirmed by the EDXS spectrum and is presented in Fig. 2(e). Hence the structural and microstructural analysis confirms the presence of individual phases in the composite samples.

**Figure 2:** Scanning electron microscope (SEM) images for (a) Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te polished pellet (b) WC powder, and (1-z)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/(z)WC composite with (c) z=0.010, (d) z=0.020 and (e) EDXS spectra for z=0.010 is shown. Inset shows the zoom-in image for z=0.010. The corresponding elemental mapping for each element present in the sample is also shown.

### 2.2. Electrical transport properties:

It is essential to have a homogeneous distribution of Seebeck coefficient ($\alpha$) for efficient energy conversion in the TE materials. The spatial distribution of $\alpha$ for (1-z)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/(z)WC sample on its surface (2.0 mm × 2.0 mm) with a step size of 50 μm is measured using the scanning thermoelectric microprobe (STM) and is shown in Fig. 3(a-c). The corresponding histogram of $\alpha$ is also presented in Fig. 3(d-f). The sample with z=0.000 shows an average value of the Seebeck coefficient ($\alpha_{av}$) ~83 μV·K$^{-1}$. The $\alpha_{av}$ increases with a small volume fraction of WC (93 μV·K$^{-1}$ for z=0.010) and then decreases (74 μV·K$^{-1}$ for z=0.020). It is noted that for the composite samples, only monomodal distribution is seen in the histogram curves. The $\alpha$ corresponding to only WC is not observed, and this may be attributed to the small particle size of WC (~150-200 nm) compared to the diameter of the tip (~50 μm). The standard deviation
increases slightly with an increase in WC volume fraction in the composite. Also, $\alpha_{av}$ decreases with higher $z$ values and is attributed to the weighted contributions of $\alpha$ from both the phases.

![Spatial distribution of the Seebeck coefficient (\(\alpha\)) and corresponding histogram curves for (1\(-z\))Ge_{0.87}Mn_{0.05}Sb_{0.08}Te/\(z\)WC composite for (a,d) $z=0.000$, (b,e) $z=0.010$, (c,f) $z=0.020$.](image)

Figure 3: Spatial distribution of the Seebeck coefficient (\(\alpha\)) and corresponding histogram curves for (1\(-z\))Ge_{0.87}Mn_{0.05}Sb_{0.08}Te/\(z\)WC composite for (a,d) $z=0.000$, (b,e) $z=0.010$, (c,f) $z=0.020$.

The electrical conductivity (\(\sigma\)) as a function of temperature for (1\(-z\))Ge_{0.87}Mn_{0.05}Sb_{0.08}Te/\(z\)WC (0\(<z<0.02\)) is shown in Fig. 4(a). The \(\sigma\) for all the samples decreases with an increase in temperature showing the degenerate semiconducting behavior. The \(\sigma\) increases with an increase in the WC volume fraction in the composite. The electrical conductivity of Ge_{0.87}Mn_{0.05}Sb_{0.08}Te at 300 K is 1150 S/cm, and it increases to 1342 S·cm\(^{-1}\) for $z=0.010$ and 1501 S·cm\(^{-1}\) for $z=0.020$. This increase in \(\sigma\) may be attributed to the high \(\sigma\) of the dispersed phase (~50,000 S·cm\(^{-1}\) for WC).\[^{33}\] The literature reports suggest that the conducting dispersed phase at the grain boundary in the composite promotes electrical connectivity to enhance electronic transport.\[^{34}\]
2.2.1. Percolation theory for electrical conductivity:

The electrical conductivity ($\sigma$) as a function of WC volume fraction at 300 K is shown in Fig.4(b). Due to microstructure features of the composite it is expected that the current will be flowing through the grain boundaries, where the amount of highly conductive WC phase is relatively high. The theoretical values of electrical conductivity of the composite is are calculated using the percolation model $^{[35]}$, given by:

$$\sigma = \sigma_m \left( \frac{z_c-z}{z_c} \right)^{-s}$$

(2)

Here $\sigma_m$, and $\sigma$ represent the electrical conductivity of the matrix, and the composite, $z$ is the volume fraction, $s$ is a constant, with a well established and universal value of 0.87$^{[35]}$. This model was fitted to the experimental data using Origin software with percolation threshold as a parameter. Line in the Fig.4(b) represents obtained values of electrical conductivity for $(1-z)$Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te$/z$WC composite with fitted percolation threshold $(z_c)$ value of 0.073 (Pearson’s correlation coefficient $R^2=0.971$). Such agreement indicates, that in investigated composite the volume fraction of WC required for creation of continuous percolation paths is relatively small ~7%vol, and amounts used in this research ($z=0.005$-$0.02$) are enough to cause a noticeable increase of composite electrical conductivity.

2.2.2. Carrier concentration and mobility:

Since electrical conductivity ($\sigma$) depends on carrier concentration ($n$), mobility ($\mu$) as $\sigma = ne\mu$, where $e$ is electronic charge.$^{[36]}$ The carrier concentration ($n$) measured using Hall measurement and corresponding carrier mobility ($\mu$) estimated using the $\sigma$ and $n$ are shown in Fig.4(c). It is found that the $\mu$ of the composite increases with an increase in the WC volume fraction. In general, the addition of the second phase creates scattering centers for charge carriers in bulk semiconducting materials and reduces $\mu$. However, a significant enhancement in electrical conductivity is obtained in the present study and is attributed to the enhanced $\mu$. A similar observation was demonstrated by Zhou et al. in Ag added skutterudites.$^{[34]}$ A scheme depicting the rise in $\mu$ in the composite sample is shown in Fig. 4(d). The increase in carrier mobility in the
composite sample may be attributed to the filtering of high energy carriers at the interface between these two phases in the composite (discussed later).\cite{37,38}

2.2.3. Seebeck coefficient and power factor:

Temperature-dependent Seebeck coefficient ($\alpha$) for (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te$/z$WC (0$\leq z$$\leq$0.02) is shown in Fig.4(e). The $\alpha$ for all samples increases with an increase in temperature and is consistent with changes in $\sigma$. Although the addition of WC improves the $\sigma$ significantly, it also enhances $\alpha$ of the composite sample up to $z$=0.010. The $\alpha$ for Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te at 300 K is $\sim$93 $\mu$V·K$^{-1}$ and increases to ($\sim$100 $\mu$V·K$^{-1}$) for the composite samples up to $z$=0.010. However, with further increase in WC volume fraction, $\alpha$ decreases to
78 µV·K⁻¹ for z=0.020. These values of α are consistent with the α₃v obtained from the STM analysis. The increase and decrease in α are consistent with the carrier concentration change in the composite (Fig.4(c)). The carrier concentration decreases up to z=0.010 and then increases. Such an increase in α for small WC volume fraction can be attributed to the carrier energy filtering effect. Li et al. showed that the addition of SiC enhanced α for PbTe based composite. Similar observation was reported in Ge₀.94Bi₀.06Te/SiC composite. The simultaneous increase in σ and α results in an enhanced power factor (α²σ), as shown in Fig.4(f). The α²σ increases with the increase in temperature up to ~700 K and then decreases. The power factor increases from 1320 µW·m⁻¹·K⁻² at 300 K and reaches ~3800 µW·m⁻¹·K⁻² at 700 K for the composite with z=0.010. Due to a significant decrease in α for higher WC volume fraction (z=0.020), the power factor reduces across the temperature range.

2.2.4. Kelvin probe force microscopy (KPFM) measurement:

It is noted that the increase in α²σ for composite is owing to a significant increase in σ. Hence a better understanding of how σ increases in the composite is required. For this purpose, we investigated the potential barrier at the interface between the Ge₀.87Mn₀.05Sb₀.08Te and WC by measuring the work function for both the individual phases using the Kelvin probe force microscopy (KPFM) technique. KPFM is a vital tool to understand the relative position of the Fermi level in solids. The work function for individual phases is calculated by measuring the contact potential difference (CPD) using the KPFM. The CPD is defined as:

\[
CPD = \frac{\phi_{sample} - \phi_{tip}}{e}
\]

where \(\phi_{tip}\) and \(\phi_{sample}\) are the work function of the atomic force microscopy (AFM) probe and sample, respectively. The work function of the AFM probe (\(\phi_{tip} = 4.15\) eV) was determined by measuring the potential map of freshly cleaved HOPG with the known value of work function (\(\phi_{HOPG} = 4.6\) eV). Further, the work functions of the samples (\(\phi_{sample}\)) are found using \(\phi_{sample} = \phi_{tip} + CPD\). The surfaces of both the samples (Ge₀.87Mn₀.05Sb₀.08Te and WC) and HOPG were scanned alternatively to determine the CPD values.
Figure 5: The spatial variation of contact potential difference (CPD) and corresponding 2-dimensional surface topography for (a,b) Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te, and (c,d) WC. The CPD histogram for (e) WC and, (f) Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te. (g) The band diagram was estimated from the work function obtained from the Kelvin probe force microscopy (KPFM) for Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te and WC. The small Fermi energy difference indicates a crossover of high-energy carriers at the interface.

The spatial variation of CPD and two-dimensional surface topography observed for both phases are shown in Fig.5(a-d). The CPD histograms for Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te and WC phases are shown in Fig.5(e-f). The work function obtained from the KPFM measurement for Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te and WC is 4.53 eV and 4.37 eV, respectively. It is worth noting that the mean values of CPD for HOPG analyzed before and after measurements are practically the same (449 mV vs. 461 mV), excluding tip contamination. The work function obtained from the KPFM measurement is used to design the band diagram for both the phases and is shown in Fig.5(g). It is noted that for the semiconductor (Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te) - metal (WC) junction, there can be either Schottky contact (work function of the metal is greater than semiconductor) or Ohmic contact (work function of semiconductor is greater than metal).$^{[42,43]}$ The present study shows that the work function for WC is smaller than Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te. It indicates that charge carriers can flow from WC to Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te, supporting the enhanced $\sigma$ in the system. Also, the energy difference ($\Delta E_i$) between these two materials is quite small (0.16 eV) that helps to enhance $\sigma$ in
the composite. This small difference in $\Delta E_f$ may scatter the lower energy carrier at the interface and allow the high energy carrier (increased $\mu$) to improve $\alpha$ due to energy filtering.\textsuperscript{[25,44]} This indicates that the small mismatch in $\Delta E_f$ enhances both $\sigma$ and $\alpha$ in the composite.

2.3. Thermal Transport Properties:

Temperature-dependent total thermal conductivity ($\kappa$) for (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/($z$)WC composite is shown in Fig.6(a). The $\kappa$ decreases with an increase in temperature for all the samples. However, it increases with the increase in WC volume fraction in composite up to 500 K and decreases with further increase in temperature for composite samples up to $z$=0.010. A noticeable increase in $\kappa$ at all temperatures is seen for the sample with $z$=0.020. This increase in $\kappa$ is logical since WC possesses very high $\kappa$ ($\sim$170 W·m$^{-1}$·K$^{-1}$) at 300 K. However, it does not follow the rule of mixture despite a significant increase in $\sigma$. Since $\kappa$ consists of electronic thermal conductivity ($\kappa_e$) and phonon thermal conductivity ($\kappa_{ph}$) components, i.e., $\kappa=\kappa_e+\kappa_{ph}$, the addition of WC volume fraction in the composite improves $\sigma$ and hence must increase $\kappa_e$. To elucidate the nature of electron and phonon contribution to thermal conductivity, both $\kappa_e$ and $\kappa_{ph}$ in the composite system are separated from $\kappa$ by calculating the $\kappa_e$ using Wiedemann Franz law $\kappa_e=L\sigma T$, where the Lorenz number ($L$) was calculated using the Snyder equation: $L = (1.5 + \exp\left[-\frac{|\alpha|}{116}\right]) \times 10^{-8}$ W·Ω·K$^{-2}$ with $\alpha$ in μV·K$^{-1}$.\textsuperscript{[45]}

2.3.1. Phonon thermal conductivity and Bruggeman’s model:

Temperature-dependent $\kappa_{ph}$ for (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/($z$)WC composite is shown in Fig.6(b). It is worth noting that $\kappa_{ph}$ of the composite decreases with the increase in temperature, and interestingly, it also decreases with the increase in WC volume fraction. The changes in electronic ($\kappa_e$) and phonon thermal conductivity ($\kappa_{ph}$) with an increase in WC volume fraction at 300 K are shown in the inset of Fig.6(b). It is noted that $\kappa_{ph}$ of WC is relatively high ($\sim$135 W·m$^{-1}$·K$^{-1}$ at 300 K) compared to Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te. However, $\kappa_{ph}$ of the composite decreases with the addition of the WC volume fraction. This decrease in $\kappa_{ph}$ for composite is
interesting and is analyzed using Bruggeman’s asymmetrical model that considers $R_{\text{int}}$ between the phases in the composite. $R_{\text{int}}$ for the composite is estimated using the AIM and the Debye model.$^{[46,47]}$ The AIM model shows that the phonon propagating from one material to another can be reflected if there is a mismatch in the acoustic impedance ($Z=\rho v$) between the two materials, where $v$ is the sound velocity, and $\rho$ is the sample density.$^{[30]}$ The sound velocity ($v$) and sample density ($\rho$) measured for both $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$ and WC and their calculated acoustic impedance are presented in Table I. The probability of phonon transmission ($\eta = pq$) at the interface between $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$ (matrix) and WC (dispersed phase) is 0.0436, where $p = \frac{4Z_AZ_B}{(Z_A+Z_B)^2}$, $q = \frac{1}{2} \left(\frac{v_m}{v_d}\right)^2$ are calculated using the sound velocity of the matrix ($v_m$) and dispersed phase ($v_d$).$^{[48]}$ The acoustic impedance for the matrix is $Z_A$ and that of the dispersed phase is $Z_B$.

Table I: The measured values of sample density ($\rho$), sound velocity ($v$) used in acoustic impedance mismatch (AIM) model to calculate the acoustic impedance ($Z$) and Transmission coefficient ($p$) of phonons for $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$ and WC samples.

<table>
<thead>
<tr>
<th>Sample Name</th>
<th>$\rho$ (g·cm$^{-3}$)</th>
<th>$v$ (m·sec$^{-1}$)</th>
<th>$Z$ (kg·m$^{-2}$·s$^{-1}$)</th>
<th>$p_{av}$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\text{Ge}<em>{0.87}\text{Mn}</em>{0.05}\text{Sb}_{0.08}\text{Te}$</td>
<td>5.74</td>
<td>1870</td>
<td>3220</td>
<td>10734</td>
</tr>
<tr>
<td>WC</td>
<td>15.43</td>
<td>4400</td>
<td>7180</td>
<td>67892</td>
</tr>
</tbody>
</table>

The probability of phonon transmission obtained from the AIM model is used to calculate the $R_{\text{int}}$ between the $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$/WC phases following the Debye model: $R_{\text{int}}=\frac{4}{\rho c_p v_D \eta}$, where $c_p$ is the specific heat capacity of the matrix, $v_D = \left(\frac{3}{\frac{1}{v_t^3}+\frac{1}{v_l^3}}\right)^{1/3}$ is the Debye velocity. Using the values of $c_p$, $\rho$, $v_D$, and $\eta$, the $R_{\text{int}}$ estimated for $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$ and WC is $2.535\times 10^{-6}$ m$^2$·K·W$^{-1}$. This value of $R_{\text{int}}$ is higher than several TE composites and is beneficial for improving phonon scattering between the composite phases.$^{[14,30]}$ The $R_{\text{int}}$ between the phases gives a critical grain size called Kapitza radius ($a_K=R_{\text{int}} \kappa_{ph,m}$) below which the $\kappa_{ph}$ of the composite reduces.$^{[27]}$ Using the phonon thermal
conductivity of the matrix ($\kappa_{ph,m}$) and $R_{int}$, $a_K$ for $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/\text{WC}$ composite is 3.40 $\mu$m at 300 K. A high $R_{int}$ provides a larger $a_K$ and it suggests that $\kappa_{ph}$ of the composite can be reduced if the particle size of the dispersed phase is smaller than 3.40 $\mu$m. The consideration of AIM and the Debye model is important to estimate the critical size for a composite to reduce its $\kappa_{ph}$.

Figure 6: (a) Total thermal conductivity ($\kappa$), (b) phonon thermal conductivity ($\kappa_{ph}$) as a function of temperature for $(1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}$ composite. Inset of (b) shows the contribution of $\kappa_e$ and $\kappa_{ph}$ at 300 K, (c) The $\kappa_{ph}$ calculated (solid lines) as a function of WC volume fraction for $(1-z)\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/(z)\text{WC}$ for the different particle size of WC, using Bruggeman’s asymmetrical model. The symbols represent the $\kappa_{ph}$ obtained from the total $\kappa$. Inset of (c) shows the $\kappa_{ph}$ calculated for composite with $z=0.020$ as a function of WC particle size. (d) A schematic of composite materials with different particle sizes of WC (red circles) is shown. The phonons are reflected for smaller WC particle size due to the prominent effect of interface thermal resistance between phases due to increased interfacial area/surface to volume ratio.

Further, Bruggeman’s asymmetrical model is used to analyze the $\kappa_{ph}$ of the $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}/\text{WC}$ composite, using $a_K$ obtained for the composite, by the formula:[$^{49}$]
\[(1 - z)^3 = \left( \frac{\kappa_{ph,m}}{\kappa_{ph,d}} \right)^{1+2\alpha} \left( \frac{\kappa_{ph} - \kappa_{ph,d}}{\kappa_{ph,m} - \kappa_{ph,d}} \right)^{\frac{3}{1-\alpha}} \] (4)

where \(\kappa_{ph,d}\) and \(\kappa_{ph}\) are the thermal conductivity of the dispersed phase (WC) and the composite, respectively, and \(\alpha = a/a_K\) where \(a\) is the particle size of the dispersed phase. \(\kappa_{ph}\) calculated using the Bruggeman’s asymmetrical model for Ge\(_{0.87}\)Mn\(_{0.05}\)Sb\(_{0.08}\)Te/WC composite with \(z=0.020\) at 300 K as a function of different particle size of WC is shown in the inset of Fig.6(c). As can be seen from the curve, \(\kappa_{ph}\) decreases with the decrease in the particle size of WC. It reduces below \(\kappa_{ph,m}\) when \(a < a_K\) (marked by the dotted line in the inset of Fig.6(c)).

Figure 6(c) depicts \(\kappa_{ph}\) as a function of WC volume fraction (\(z\)) for the different particle size of WC at 300 K. The \(\kappa_{ph}\) increases when \(a > a_K \sim 3.40\ \mu m\). It indicates that even a higher acoustic mismatch between Ge\(_{0.87}\)Mn\(_{0.05}\)Sb\(_{0.08}\)Te and WC phases is present, \(\kappa_{ph}\) increases when \(a > a_K\). However, \(\kappa_{ph}\) remains the same for \(a \sim a_K\). It decreases when \(a < a_K\) and indicates that \(R_{int}\) becomes prominent for \(a < a_K\) and hence reduces \(\kappa_{ph}\). It also suggests a strong correlation between \(R_{int}\) and \(a_K\).\(^{[14]}\) In other words, the smaller particle size of the dispersed phase enhances the surface to volume ratio and hence prominently reduces \(\kappa_{ph}\). A schematic of Ge\(_{0.87}\)Mn\(_{0.05}\)Sb\(_{0.08}\)Te/WC composite for the different particle sizes of WC is shown in Fig.6(d). It shows that the larger particle size of the dispersed phase possesses a lower interface area, which leads to an increase in \(\kappa_{ph}\) even if \(R_{int}\) is high. On the other hand, if the particle size of the dispersed phase is smaller than \(a_K\), the \(R_{int}\) becomes prominent with increased interface area/surface to volume ratio and reduces \(\kappa_{ph}\).

2.4. Figure of Merit and Efficiency:

Using the experimentally observed TE parameters: \(\alpha\), \(\sigma\), and \(\kappa\), the figure of merit (\(zT\)) of the composite is calculated and is shown in Fig.7(a). The \(zT\) increases with an increase in temperature for all the samples. The \(zT\) also increases with WC volume fraction and shows a maximum of 1.93 at 773 K for the sample with \(z=0.010\). This enhancement in \(zT\) is attributed to the simultaneous rise in \(\sigma\) and \(\alpha\) for composite along with reduced \(\kappa_{ph}\) owing to the AIM.
between the phases. However, the higher WC fraction in the composite reduces $zT$ due to a significant reduction in $\alpha$.

Figure 7. (a) Figure of merit ($zT$) (b) average $zT$ for the (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/$z$WC composite, (c) average $zT$ compared with the values reported in the literature$^{50-54}$, (d) The energy conversion efficiency calculated considering similar n-type leg for (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/$z$WC composite.

The energy conversion efficiency of TE devices made up of TE materials is defined as

$$\eta = \frac{\Delta T}{T_H} \frac{1}{\sqrt{1+zT_{av}}} \frac{1}{\sqrt{1+zT_{av}+zT_{av}}} \frac{1}{zT_{av}} \int_{T_C}^{T_H} zT\,dT$$

This expression suggests that a high $\eta$ requires a high average

$$(zT_{av} = \frac{1}{T_H-T_C} \int_{T_C}^{T_H} zT\,dT)$$

across a wide temperature difference ($\Delta T = T_H - T_C$) between the hot ($T_H$) and cold ($T_C$) temperature ends of the device. The $zT_{av}$ calculated for the (1-$z$)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/$z$WC composite with 300 K and 773 K as $T_C$ and cold $T_H$, respectively, is shown in Fig.7(b). The $zT_{av}$ also increases for the sample with $z=0.010$. It reaches ~1.02 for a
temperature difference of 473 K. The obtained $zT_{av}$ in the present study is higher than reported in several promising literature reports.$^{[50–54]}$ A comparison for the same is shown in Fig. 7(c). Further, using the $zT_{av}$ obtained in the present study for p-type material and assuming a corresponding similar n-type leg, theoretical energy conversion efficiency ($\eta$) is calculated for the temperature difference ($\Delta T$) between the hot and cold end temperature and shown in Fig. 7(d). A maximum energy conversion efficiency $\sim$14% is obtained for (1-$z$)$\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$/($z$)WC for $z=0.010$ composite and is higher than several promising TE materials reported in the literature.$^{[50–54]}$

3. Conclusion

This study demonstrates the influence of work function and acoustic impedance mismatch (AIM) on electronic and phonon transport properties, respectively, in $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$/WC composite. X-ray diffraction analysis confirms the individual phases in the composite, which is further supported by electron microscopy images and energy dispersive x-ray spectroscopy analysis. Enhancement in the composite's electrical conductivity ($\sigma$) is attributed to the increase in carrier mobility ($\mu$). It is also analyzed using the work function measurement by the Kelvin probe force microscopy technique. The lower work function of WC compared to $\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$ gives high mobility charge carriers to the system, and hence $\sigma$ increases. The AIM between the composite phases leads to a high interface thermal resistance ($R_{\text{int}}$), beneficial for improving phonon scattering. A correlation between $R_{\text{int}}$ and the Kapitza radius ($a_K$) decreases the phonon thermal conductivity ($\kappa_{\text{ph}}$) of the composite, supported by Bruggeman’s asymmetrical model. The simultaneous effect of work function and AIM due to WC leads to improved power factor and reduced $\kappa_{\text{ph}}$. A maximum $zT$ of 1.93 at 773 K with a $zT_{av} \sim 1.02$ for a temperature difference of 473 K is obtained for (1-$z$)$\text{Ge}_{0.87}\text{Mn}_{0.05}\text{Sb}_{0.08}\text{Te}$/($z$)WC with $z=0.010$. It results in the maximum energy conversion efficiency ($\eta$) of $\sim$14%. This study shows promise to develop efficient thermoelectric composite materials further having similar electronic structure and different elastic properties (considering the correlation between $R_{\text{int}}$ and $a_K$).
4. Experimental Section

The synthesis of Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te has been carried out by the direct melting of elements (Ge, Mn, Sb, and Te) with purity >99.99% (Alfa Aesar) in evacuated quartz ampoules following our previous report in GeTe.$^{[32]}$ Further, the (1-z)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/zWC composite with z=0.000, 0.005, 0.010, and 0.020 is prepared by mixing the different volume percentage of WC (Sigma Aldrich, 99.9%). The composite mixture was ground to mix homogeneously in a liquid medium (acetone) using a mortar-pestle. The mixture was then sintered using pulsed electric current sintering (PECS) technique in Ar (5N) atmosphere at 873 K for 5 minutes under a uniaxial pressure of 50 MPa with a heating cooling rate of 70 K/min and 50 K/min, respectively. The obtained cylindrical pellets of 10 mm diameter and 12 mm length were cut to proper dimensions using a precise wire saw for further measurements. The surface morphology and chemical analysis of the polished sample surface were done using a scanning electron microscope (SEM, NOVA NANO 200, FEI EUROPE Company) equipped with an EDXS analyzer. The X-ray diffraction of samples was obtained by the D8 ADVANCE (BRUKER) diffractometer using Ni-filtered Cu-Kα radiation (λ=1.5406 Å). The spatial variation of Seebeck coefficient for the (1-z)Ge$_{0.87}$Mn$_{0.05}$Sb$_{0.08}$Te/zWC composite was done using a scanning thermoelectric microprobe (STM) at 300 K with a spatial resolution of 50 µm. Thermal diffusivity for all the samples was measured using the laser flash analysis (LFA-457, NETSCH) apparatus in the Ar (5N) atmosphere (30 ml/min). Specific heat was determined simultaneously with the thermal diffusivity using pyroceram 9606 as reference material. The sample density was measured using sample mass and its geometric volume. Electrical conductivity and Seebeck coefficient were measured under Ar (5N) atmosphere (50 ml/min) by the SBA 458 (NETSCH) apparatus. The uncertainty of the Seebeck coefficient and electrical conductivity measurements is 7% and 5%, respectively. The estimated uncertainty in thermal conductivity is 7%. The carrier concentration was measured at 300 K using physical properties measurement system (PPMS, Quantum Design) under the magnetic field of ±3 T. Work function measurements were performed using atomic force microscope (Dimension ICON, Bruker) working in the Peak Force KPFM mode. PFQNE-AL probes (with a nominal spring constant of 0.8 N/m) were used for capturing of topography and potential maps under ambient conditions. The images were captured with the resolution of 84 x 256 pixels. The work function of AFM tip (φtip = 4.15 eV) was determined by measuring the CPD of freshly cleaved HOPG with known value of work function (4.6 eV). The CPDs of HOPG before and after measurements were virtually the same (0.45 V and 0.46 V) excluding tip contamination. The work function of the analyzed sample was calculated using equation 2.
Declaration of Competing Interest

The authors declare no competing financial interests.

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